

Super-Junction Power MOSFET

Rev.02 - 24 July 2024

Product data sheet

1. General description

WSJM65R360S is a high voltage N-channel MOSFET in TO252 package, which utilizes the advanced super-junction technology to provide superior FOM $R_{\scriptscriptstyle DS(on)}{}^*Q_{\scriptscriptstyle g}$ among silicon based MOSFETs. It is particularly suitable for applications require extreme high efficiency and power density.



2. Features and benefits

- Superior FOM $R_{\text{DS(on)}} * Q_{\text{g}}$ Extremely low switching loss
- 100% avalanche tested

3. Applications

- Chargers
 - Adapters
- Lighting
- Flyback topologies for high efficiency power supplies

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes		Values		Unit
Absolute	e maximum rating						
V _{DS}	drain-source voltage				650		V
V_{GS}	gate-source voltage				±30		V
I _D	continuous drain current	T _{mb} = 25 °C			11		А
P _{tot}	power dissipation	T _{mb} = 25 °C			113		W
T _j	junction temperature			-55 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics		•				
$R_{\text{DS(on)}}$	drain-source on-state resistance	V _{GS} = 10 V, I _D = 5.5 A		-	335	360	mΩ
Dynamic	characteristics		·		·		·
Q _{G(tot)}	total gate charge	$I_{\rm D}$ = 5.5 A; $V_{\rm DS}$ = 400 V; $V_{\rm GS}$ = 10 V		-	18	-	nC
E _{oss}	coss stored erergy	$V_{GS} = 0 V; V_{DS} = 0 to 400 V$		-	2.6	-	μJ

5. Pinning information Table 2 Pinnin

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	G	gate	ГЛ	D	
2	D	drain			
3	S	source			
mb	D	mounting base; connected to drain		svm300 S	

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WSJM65R360S	TO252	WSJM65R360SJ	Reel	2500	TO252N	14-Nov-2016		

7. Marking

Marking codes
WSJM 65R360

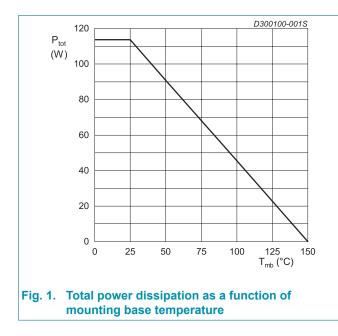
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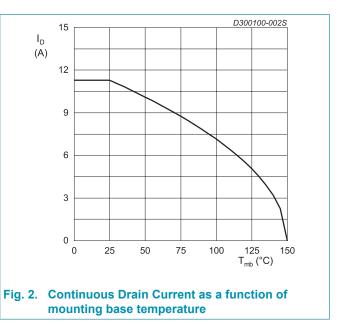
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

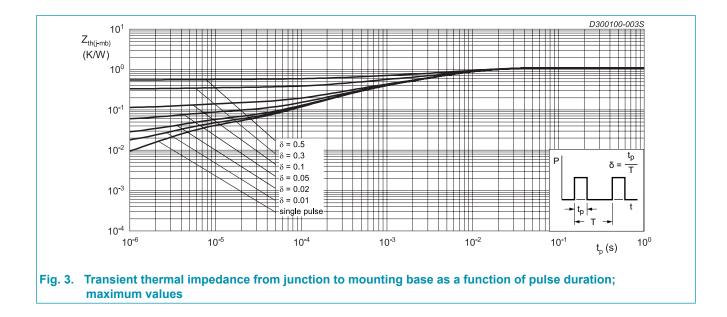
Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			650	V
V_{GS}	gate-source voltage			±30	V
I _D	continuous drain current	T _{mb} = 25 °C		11	А
		T _{mb} = 100 °C		7.1	А
I _{DM}	pulsed drain current	T _{mb} = 25 °C		44	А
P _{tot}	power dissipation	T _{mb} = 25 °C		113	W
E _{AS}	single pulse drain-to-source avalanche	I_{AS} = 3.3 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		54	mJ
E _{AR}	repetitive avalanche energy	I_{AS} = 3.3 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		0.71	mJ
I _{AS}	avalanche current, single pulse			3.3	A
dv/dt	MOSFET dv/dt ruggedness			50	V/ns
dv/dt	reverse diode dv/dt			15	V/ns
dl _F /dt	maximum diode commutation speed			500	A/µs
T _{stg}	storage temperature			-55 to 150	°C
Tj	junction temperature			-55 to 150	°C





9. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base			-	0.82	1.1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	50	-	K/W

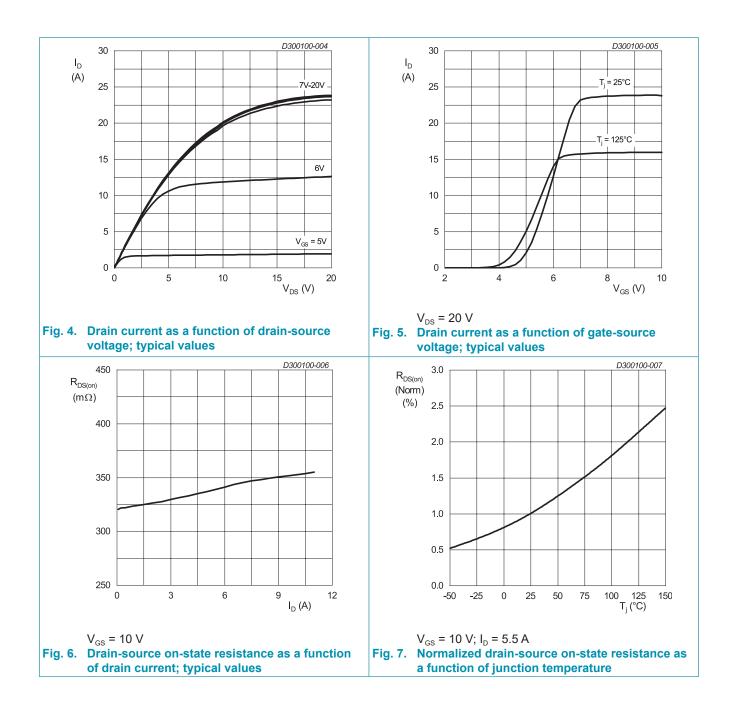


10. Characteristics

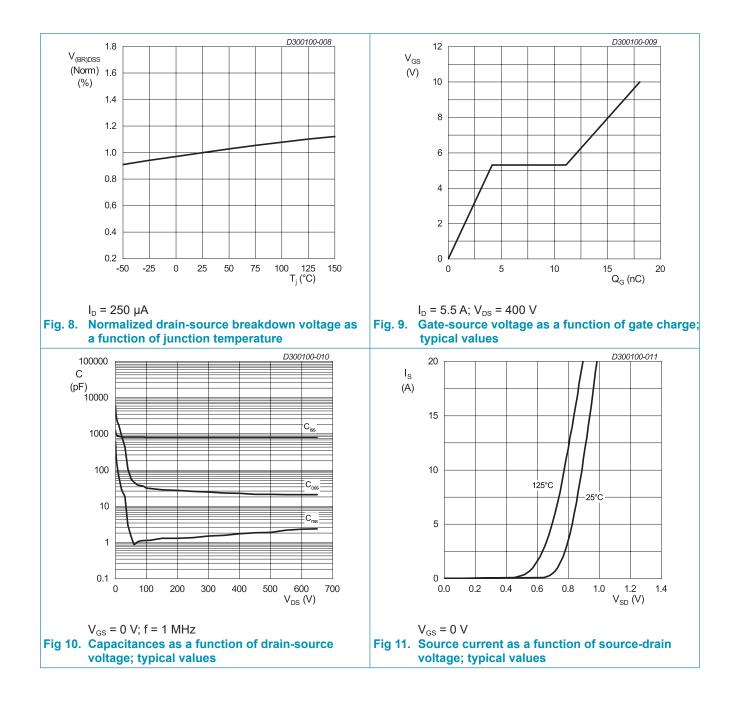
Table 7. Characteristics

	unless otherwise noted		1				
Symbol		Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V		650	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS}		2.5	-	4.5	V
I _{DSS}	drain leakage current	$V_{\rm DS}$ = 650 V; $V_{\rm GS}$ = 0 V		-	-	1	μA
		V_{DS} = 650 V; V_{GS} = 0 V; T_j = 125 °C		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 30 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
$R_{\text{DS(on)}}$	drain-source on-state resistance	V_{GS} = 10 V; I _D = 5.5 A		-	335	360	mΩ
R_{G}	gate resistance	f = 1 MHz		-	18	-	Ω
Dynamic	characteristics						1
Q _{G(tot)}	total gate charge	$I_{\rm D}$ = 5.5 A; $V_{\rm DS}$ = 400 V; $V_{\rm GS}$ = 10 V		-	18	-	nC
Q_{GS}	gate-source charge			-	4.1	-	nC
Q_{GD}	gate-drain charge			-	7.0	-	nC
C _{iss}	input capacitance	V _{DS} = 400 V; V _{GS} = 0 V; f = 1 MHz		-	808	-	pF
C_{oss}	output capacitance			-	23	-	pF
C _{rss}	reverse transfer capacitance			-	1.8	-	pF
$C_{\text{o}(\text{er})}$	effective output capacitance, energy related	V_{GS} = 0 V; V_{DS} = 0 to 400 V		-	33	-	pF
$C_{o(tr)}$	effective output capacitance, time related			-	148	-	pF
t _{d(on)}	turn-on delay time	$V_{\rm DS} = 400 \text{ V}; V_{\rm GS} = 10 \text{ V}; \text{ R}_{\rm G} = 2 \Omega;$		-	30	-	ns
t _r	rise time	$I_{D} = 5.5 A$		-	9.6	-	ns
$t_{\rm d(off)}$	turn-off delay time			-	52	-	ns
t _f	fall time			-	14	-	ns
Source-o	drain diode						
$V_{\rm SD}$	source-drain voltage	V _{GS} = 0 V; I _S = 5.5 A		-	0.8	1.1	V
ls	body-diode continuous current	T _{mb} = 25 °C		-	-	11	A
t _{rr}	reverse recovery time	V_{R} = 400 V; I_{F} = 5.5 A; dI_{F}/dt = 100 A/µs		-	229	-	ns
Q _{rr}	reverse recovered charge			-	2.3	-	μC
I _{rrm}	reverse recovery current			-	20	-	А

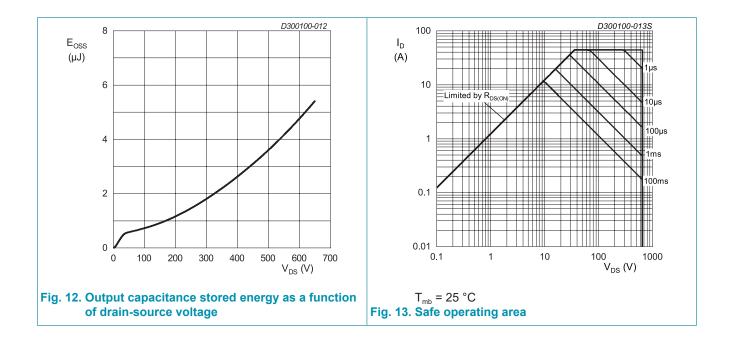
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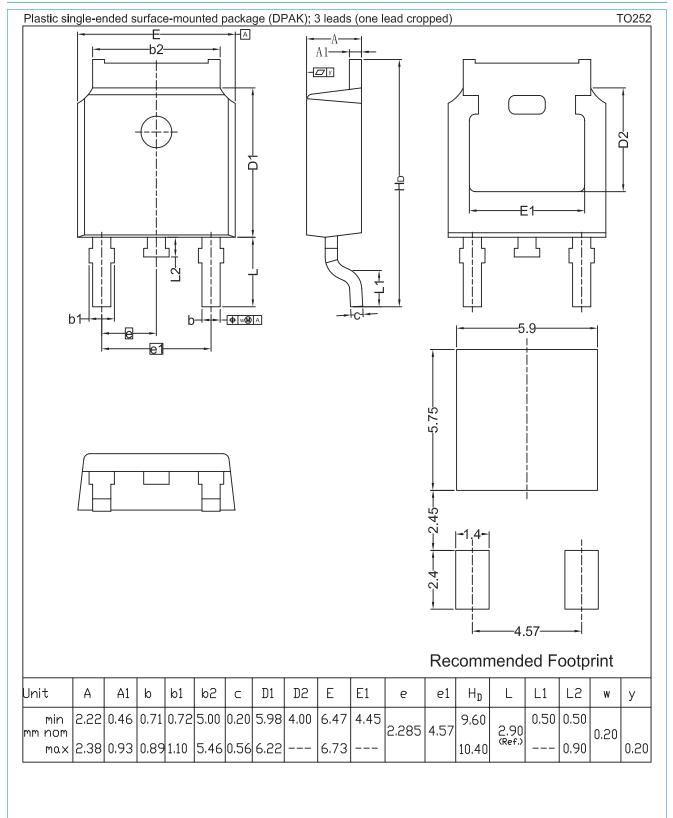


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11. Package outline



WSJM65R360S

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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